

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

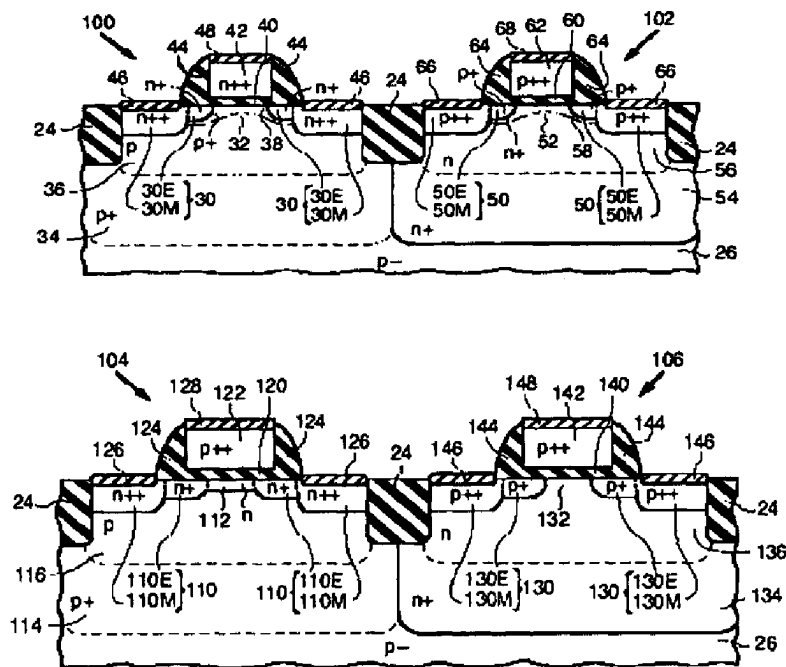
PATENT NO. : 7,176,530 B1
APPLICATION NO. : 10/803203
DATED : February 13, 2007
INVENTOR(S) : Bulucea et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

The title should read "SEMICONDUCTOR STRUCTURE HAVING N-CHANNEL CHANNEL-JUNCTION FIELD-EFFECT TRANSISTOR".

The drawing on the cover page should be:



Signed and Sealed this

Twenty-eighth Day of July, 2009

John Doll

JOHN DOLL
Acting Director of the United States Patent and Trademark Office